

## Low Voltage, Dual DPDT in miniQFN16

### DESCRIPTION

The DG2599 is a  $C_{MOS}$  Dual DPDT (Dual Double Pole Double Throw) analog switch that operates over a wide voltage range of 1.65 V to 5 V. It is optimized for portable applications switching audio, SIM card signals, and other low power signals.

The DG2599 features low ON resistance of  $2.8\ \Omega$  at 3 V power supply, fast switching speed, and low power consumption even when control logic signals are below  $V+$  power supply voltage. The well matched dual DPDT switches conduct signals equally in both directions. The DG2599 is designed to guarantee break before make switching.

As a committed partner to the community and the environment, Vishay Siliconix manufactures this product with lead (Pb)-free device terminations. DG2599 are offered in a miniQFN package. The miniQFN package has a nickel palladium- gold device termination and is represented by the lead (Pb)-free “-E4” suffix. The nickel-palladium-gold device terminations meet all JEDEC standards for reflow and MSL ratings.

### FEATURES

- **Halogen-free according to IEC 61249-2-21 definition**
- Low voltage operation - 1.65 V to 5 V
- Low on-resistance -  $2.8\ \Omega$  at  $V+ = 3\text{ V}$
- Power off protection on COM1 and COM2 pins
- Latch up current great than 300 mA per JESD78
- **Compliant to RoHS Directive 2002/95/EC**



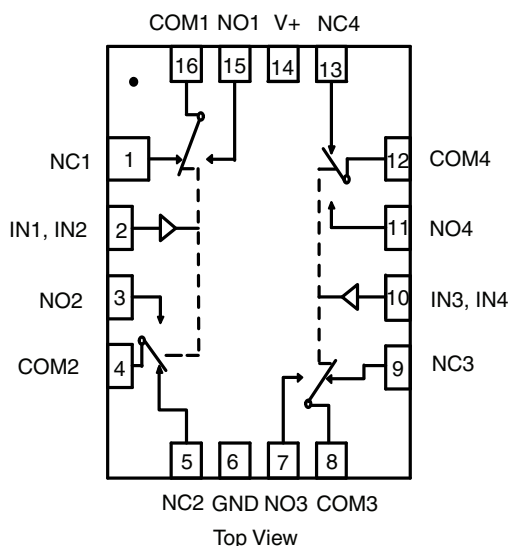
**RoHS**  
COMPLIANT  
HALOGEN  
FREE

### APPLICATIONS

- Cellular phones
- PMPs and PDAs
- Modems and peripherals
- Computers and ebooks
- Tablet devices
- Displays and gaming
- STB

### ORDERING INFORMATION

Part Number	Package
DG2599DN-T1-GE4	miniQFN16 1.8 mm x 2.6 mm

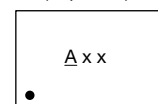


### TRUTH TABLE (DG2599)

Logic	NC1, 2, 3 and 4	NO 1, 2, 3 and 4
0	ON	OFF
1	OFF	ON

Device Marking: A xx  
xx = Date/Lot Traceability Code

(Top View)



Pin 1

Note: Pin 1 has long lead

**ABSOLUTE MAXIMUM RATINGS** ( $T_A = 25^\circ\text{C}$ , unless otherwise noted)

Parameter	Symbol	Limit	Unit
Reference to GND	V+	- 0.3 to 5	V
	IN, COM, NC, NO <sup>a</sup>	- 0.3 to (V+ + 0.3)	
Current (any terminal except NO, NC or COM)		30	mA
Continuous Current (NO, NC, or COM)		± 300	
Peak Current (pulsed at 1 ms, 10 % duty cycle)		± 500	
Storage Temperature (D Suffix)		- 65 to 150	°C
Package Solder Reflow Conditions <sup>d</sup>	miniQFN16	250	
Power Dissipation (Packages) <sup>b</sup>	miniQFN16 <sup>c</sup>	525	mW

Notes:

a. Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.

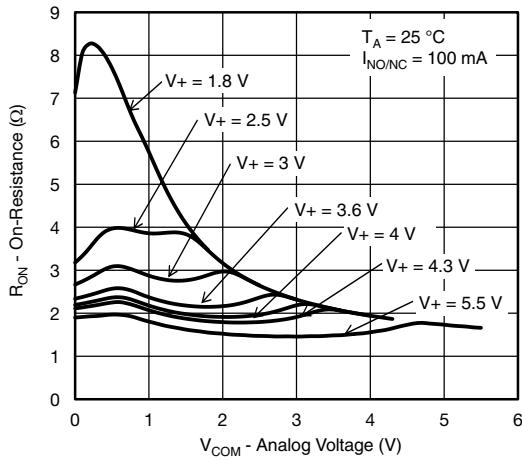
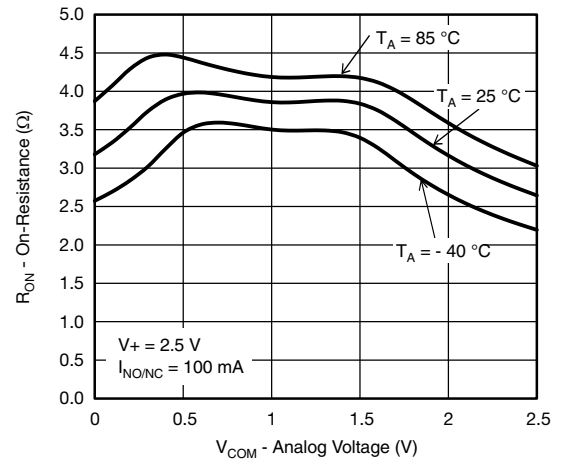
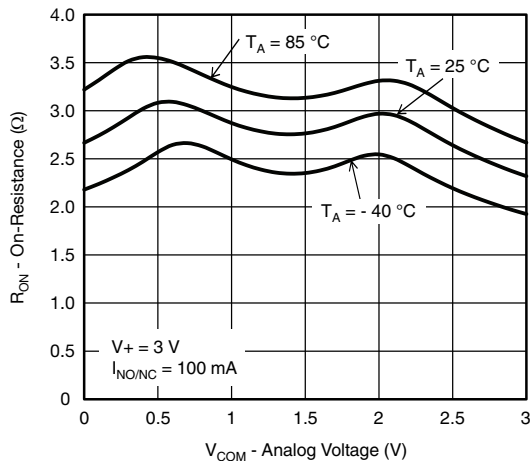
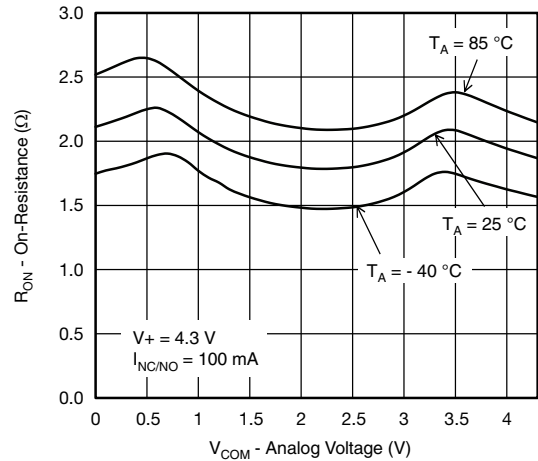
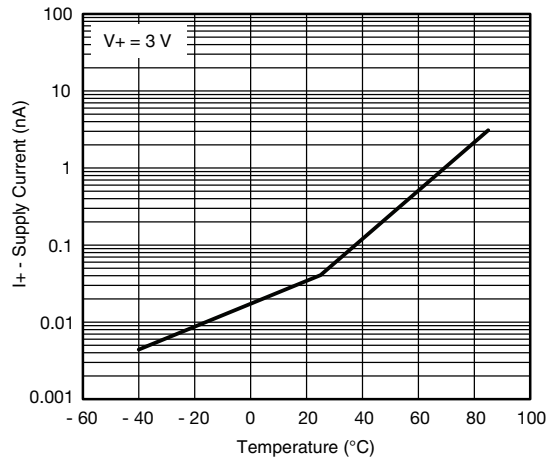
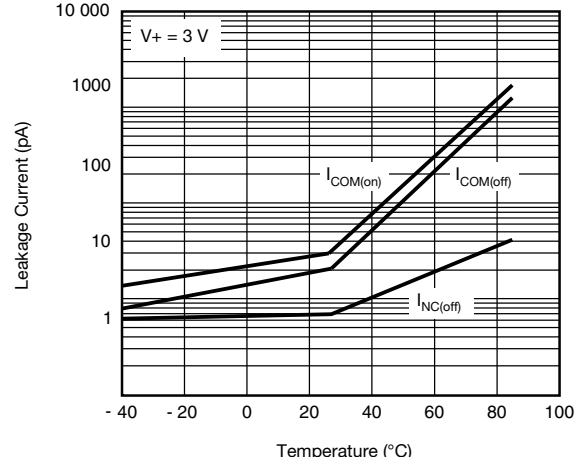
b. All leads welded or soldered to PC board.

c. Derate 6.6 mW/°C above 70 °C.

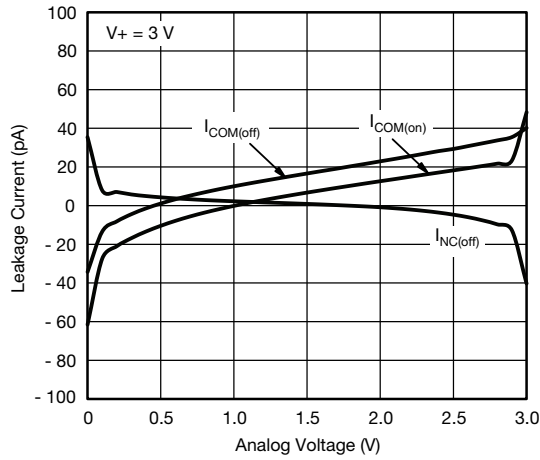
d. Manual soldering with iron is not recommended for leadless components. The miniQFN-16 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper lip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

**ELECTRICAL CHARACTERISTICS** (V+ = 3 V)

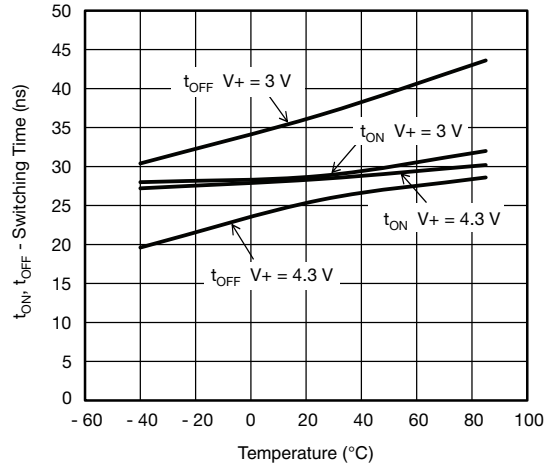
Parameter	Test Conditions	Temp.	Min.	Typ.	Max.	Unit
Power Supply and Signal						
V+ Supply Voltage		Full	1.65		5	V
V+ Supply Current	V <sub>IN</sub> = 0 or V+	Full		0.001	2	μA
Analog Signal Range		Full	0		V+	V
Switch On-Resistance and Leakage						
Drain-Source On-Resistance	V+ = 3 V, I <sub>NO/NC</sub> = 100 mA, V <sub>COM</sub> = 0.9 V, 2.3 V	Room		2.8	3.3	Ω
		Full			3.6	
On-Resistance Flatness	V+ = 3 V, I <sub>NO/NC</sub> = 100 mA, V <sub>COM</sub> = 0 to V+	Room		0.24	1.1	
		Full			1.3	
Switch Off Leakage Current	V+ = 4.3 V, V <sub>NO/NC</sub> = 0.3 V/4 V, V <sub>COM</sub> = 4 V / 0.3 V	Room	- 10	0.1	10	nA
		Full	- 100		100	
Channel On-Leakage Current	V+ = 4.3 V, V <sub>NO/NC</sub> and V <sub>COM</sub> = 0.3 V / 4 V	Room	- 10	0.1	10	
		Full	- 100		100	
Digital Control						
Input, High Voltage	V+ = 4.3 V	Full	1.6			V
	V+ = 3 V		1.3			
Input, Low Voltage	V+ = 4.3 V	Full			0.6	
	V+ = 3 V				0.5	
Input, Bias Current	V <sub>IN</sub> = V+	Full	- 1	0.01	1	μA
Dynamic Characteristics						
Turn On-Time	V <sub>COM</sub> or V <sub>NO/NC</sub> = 3 V, R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 35 pF	Room			90	ns
		Full			115	
Turn Off-Time	V <sub>COM</sub> or V <sub>NO/NC</sub> = 3 V, R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 35 pF	Room			70	
		Full			85	
Break Before Make Time	V <sub>COM</sub> or V <sub>NO/NC</sub> = 3 V, R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 35 pF	Room	2			
		Full	2			
Charge Injection	C <sub>L</sub> = 1 nF, R <sub>GEN</sub> = 0 Ω	Room		± 10		pC
Off Isolation	R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 5 pF, f = 1 MHz			- 66		dB
Crosstalk	R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 5 pF, f = 1 MHz Non-adjacent channels			- 110		
3dB Bandwidth	C <sub>L</sub> = 5 pF, R <sub>L</sub> = 50 Ω			186		MHz
Source Off Capacitance	V <sub>IN</sub> = 0 or V+, f = 1 MHz			9		pF
Channel On Capacitance	V <sub>IN</sub> = 0 or V+, f = 1 MHz			26		

**TYPICAL CHARACTERISTICS** ( $T_A = 25\text{ }^{\circ}\text{C}$ , unless otherwise noted)

 **$R_{ON}$  vs.  $V_{COM}$  and Single Supply Voltage**

 **$R_{ON}$  vs. Analog Voltage and Temperature**

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 **$R_{ON}$  vs. Analog Voltage and Temperature**

**Supply Current vs. Temperature**

**Leakage Current vs. Temperature**

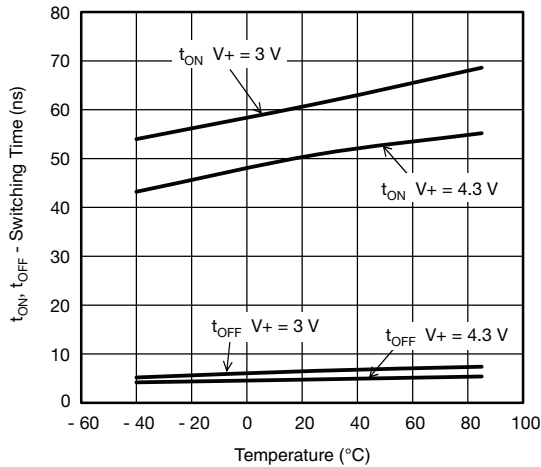
**TYPICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$ , unless otherwise noted)



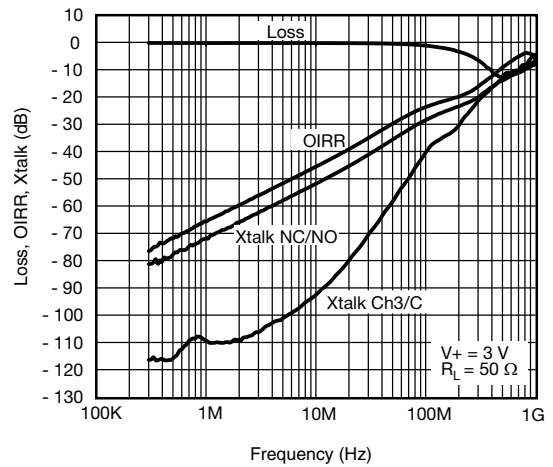
Leakage vs. Analog Voltage



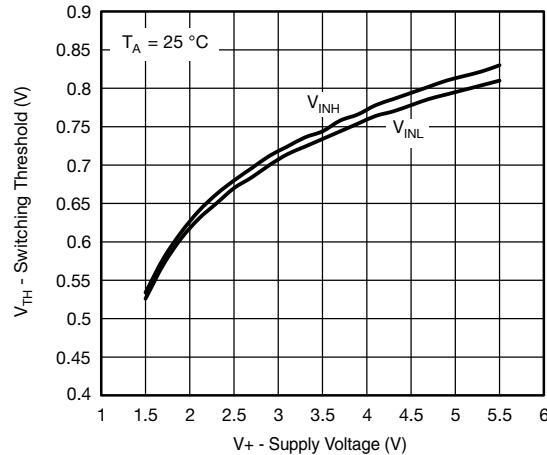
(NO) Switching Time vs. Temperature



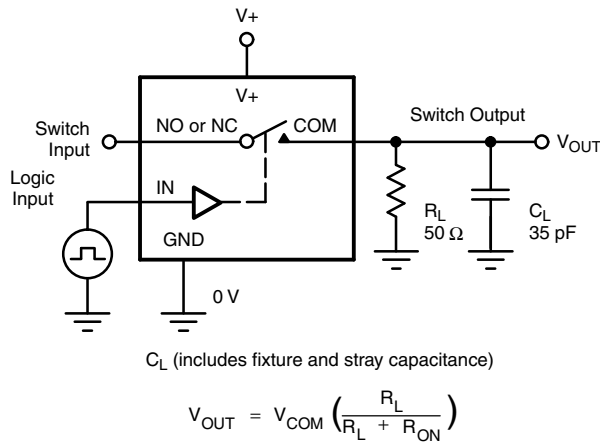
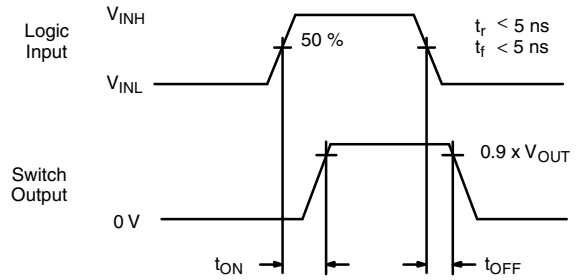
(NC) Switching Time vs. Temperature



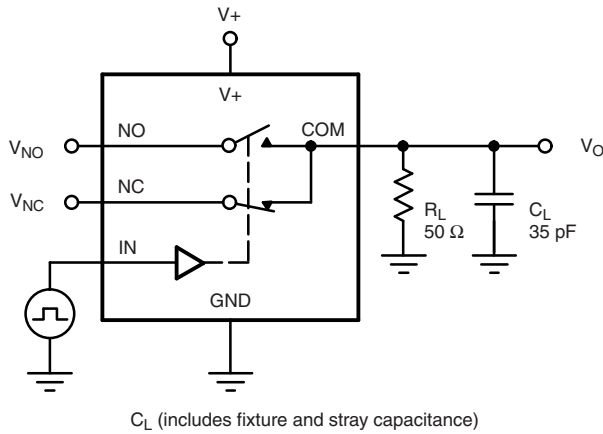
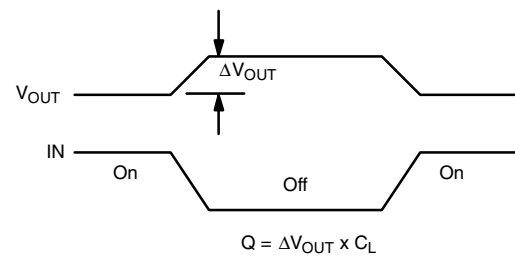
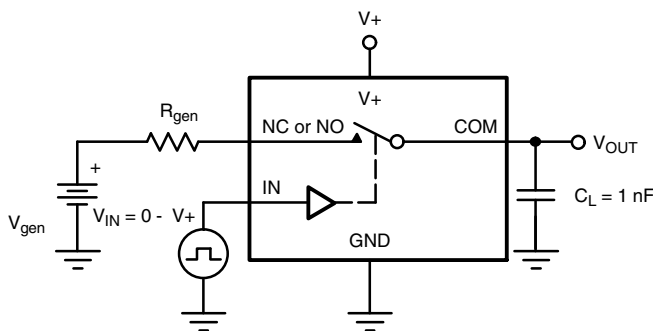
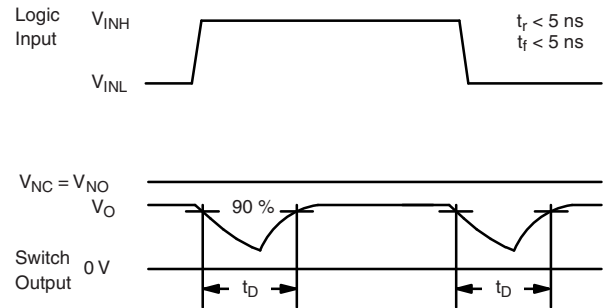
Insertion Loss, Off Isolation and Crosstalk



Switching Threshold vs. Supply Voltage

**TEST CIRCUITS**

**Figure 1. Switching Time**


Logic "1" = Switch On  
Logic input waveforms inverted for switches that have the opposite logic sense.


**Figure 2. Break-Before-Make Interval**


IN depends on switch configuration: input polarity determined by sense of switch.

**Figure 3. Charge Injection**

## TEST CIRCUITS

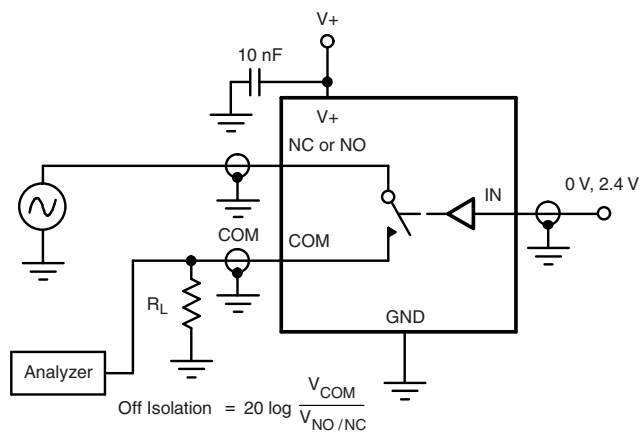


Figure 4. Off-Isolation

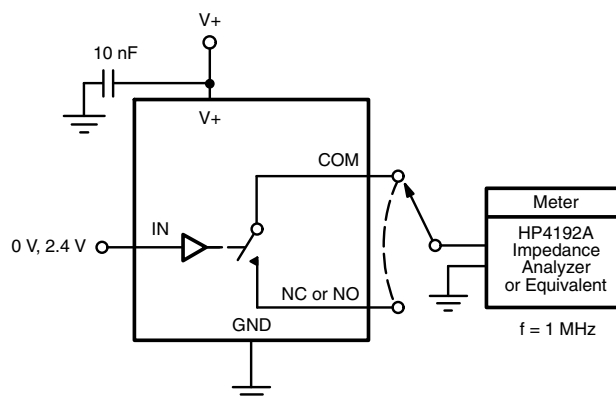
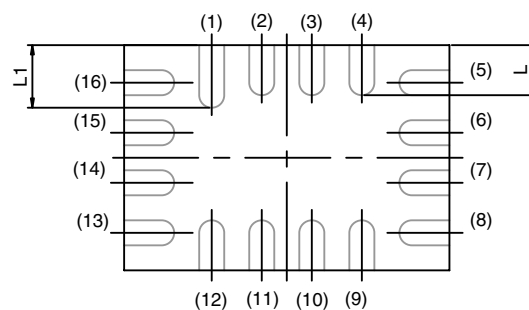
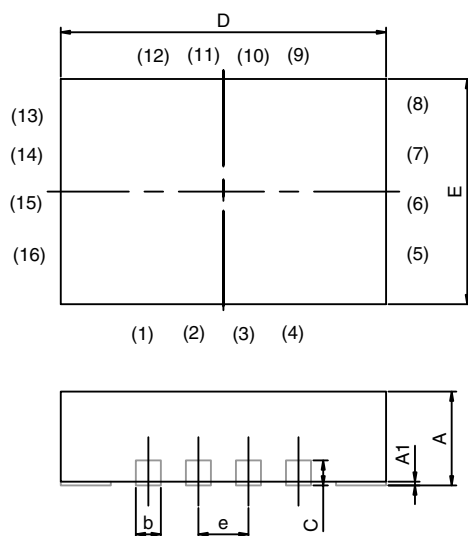


Figure 5. Channel Off/On Capacitance

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## MINI QFN-16L

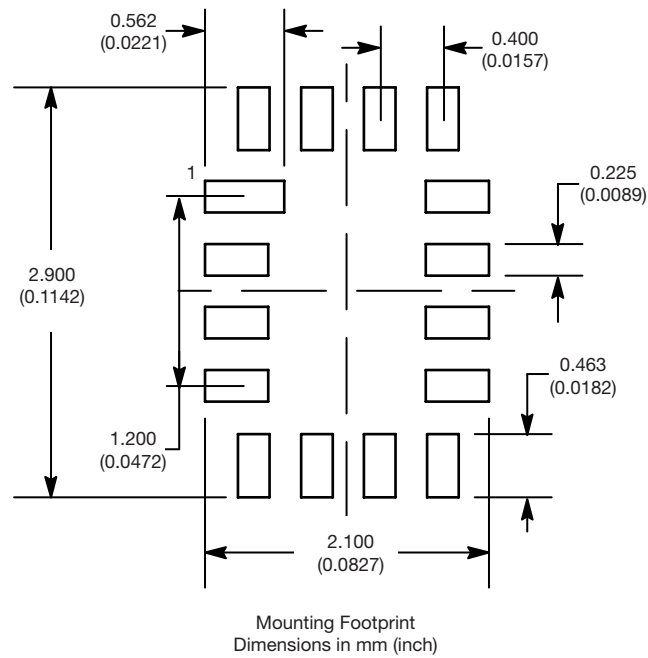


BACK SIDE VIEW

DIM	MILLIMETERS			INCHES		
	MIN.	NAM	MAX.	MIN.	NAM	MAX.
A	0.70	0.75	0.80	0.0275	0.0295	0.0315
A1	0	-	0.05	0	-	0.002
b	0.15	0.20	0.25	0.0059	0.0078	0.0098
C	0.15	0.20	0.25	0.0059	0.0078	0.0098
D	2.60 BSC			0.1023 BSC		
E	1.80 BSC			0.0708 BSC		
e	0.40 BSC			0.0157 BSC		
L	0.35	0.40	0.45	0.0137	0.0157	0.0177
L1	0.45	0.50	0.55	0.0177	0.0196	0.0216

ECN T-06380-Rev. A, 14-Aug-06  
DWG: 5954

## RECOMMENDED MINIMUM PADS FOR MINI QFN 16L







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